

Supplementary Materials

Efficient and Stable Fiber Dye-Sensitized Solar Cells Based on Solid-State Li-TFSI Electrolytes with 4-Oxo-TEMPO Derivatives

Pyeongje An ^{1,2,†}, Jae Ho Kim ^{1,†}, Myeonghwan Shin ^{3,†}, Sukyeong Kim ¹, Sungok Cho ¹, Chaehyun Park ^{1,2}, Geonguk Kim ^{1,2}, Hyung Woo Lee ^{2,4,*}, Jin Woo Choi ^{1,*}, Chuljin Ahn ^{3,*} and Myungkwan Song ^{1,*}

- ¹ Department of Energy & Electronic Materials, Korea Institute of Materials Science (KIMS), Changwon 51508, Gyeongsangnam-do, Korea; apj6669@kims.re.kr (P.A.); jho83@kims.re.kr (J.H.K.); chae119@kims.re.kr (S.K.); choso1225@kims.re.kr (S.C.); tlsaughks98@naver.com (C.P.); rndndndnr2@kims.re.kr (G.K.)
- ² Department of Nano Fusion Technology, Pusan National University, Busan 46241, Korea
- ³ Department of Biology and Chemistry, Changwon National University, Changwon 51140, Gyeongsangnam-do, Korea; a463489@kims.re.kr
- ⁴ Department of Nanoenergy Engineering and Research Center of Energy Convergence Technology, Pusan National University, Busan 46241, Korea
- * Correspondence: lhw2010@pusan.ac.kr (H.W.L.); jinwoo.choi@kims.re.kr (J.W.C.); cjahn@changwon.ac.kr (C.A.); smk1017@kims.re.kr (M.S.)
- † These authors contributed equally to this work.

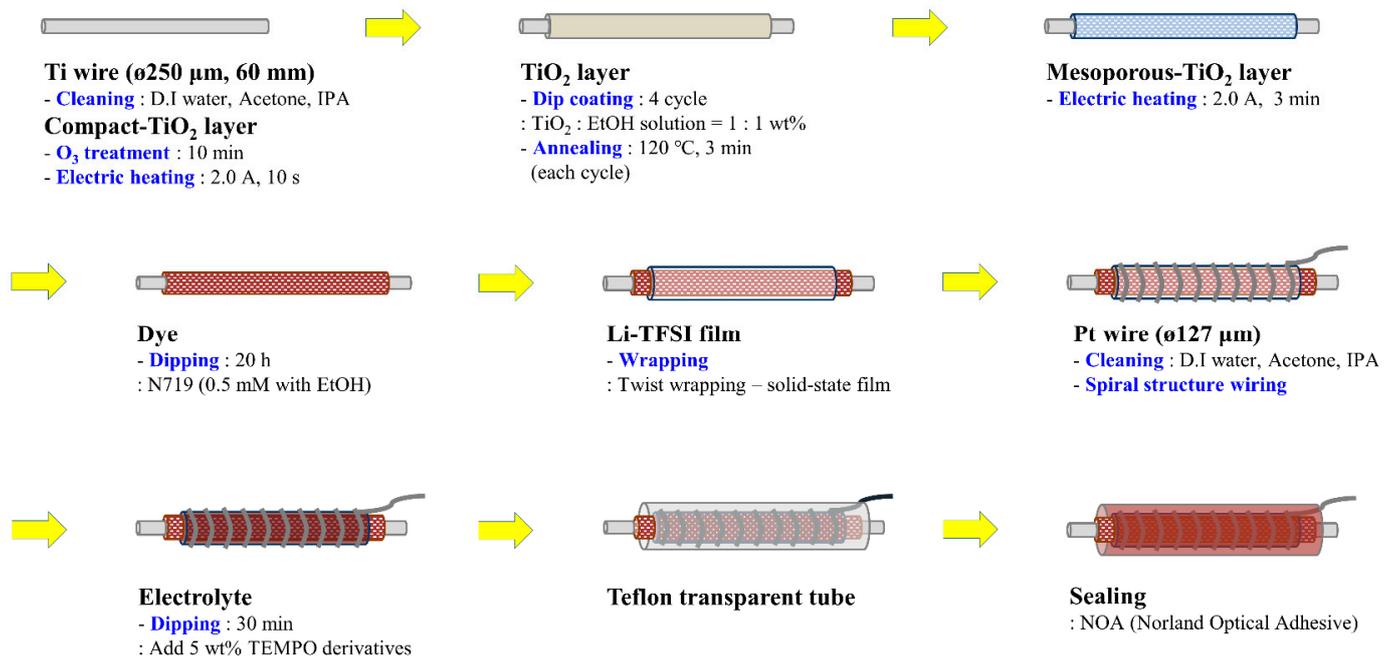


Figure S1. Fabrication process of TEMPO based SS-FDSSCs.

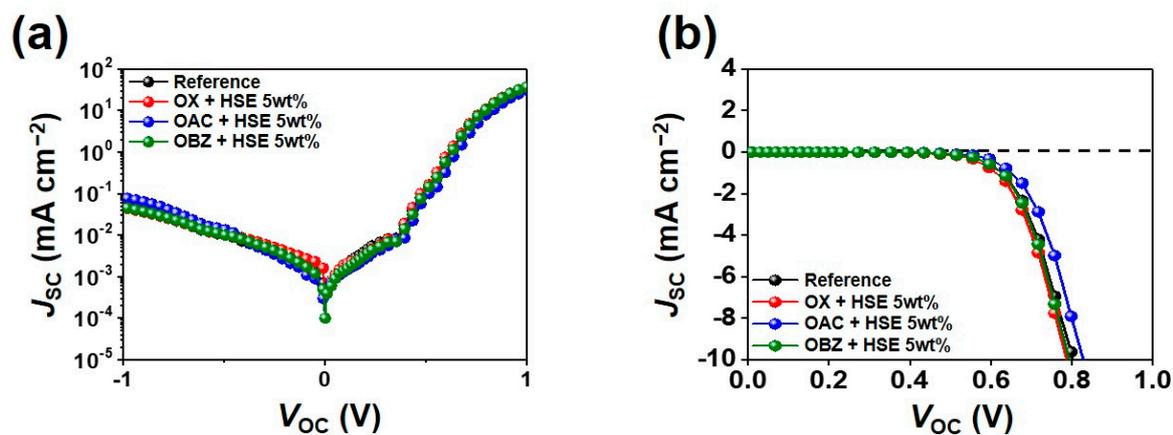


Figure S2. J - V characteristics of TEMPO-based SS-FDSSCs in the dark condition: (a) typical semi-logarithmic scale from -1 V to +1 V and (b) normal scale.

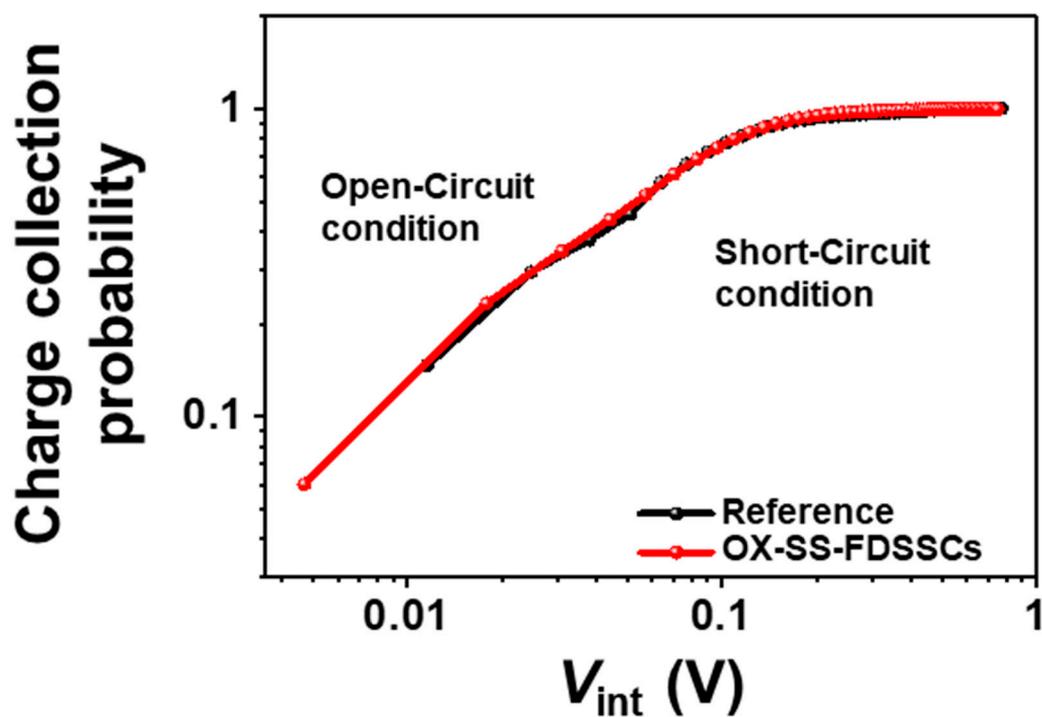


Figure S3. Characterization and photovoltaic properties of TEMPO-SS-FDSSCs devices: charge collection probability (or) normalized photocurrent with saturated photocurrent as a function of internal voltage.

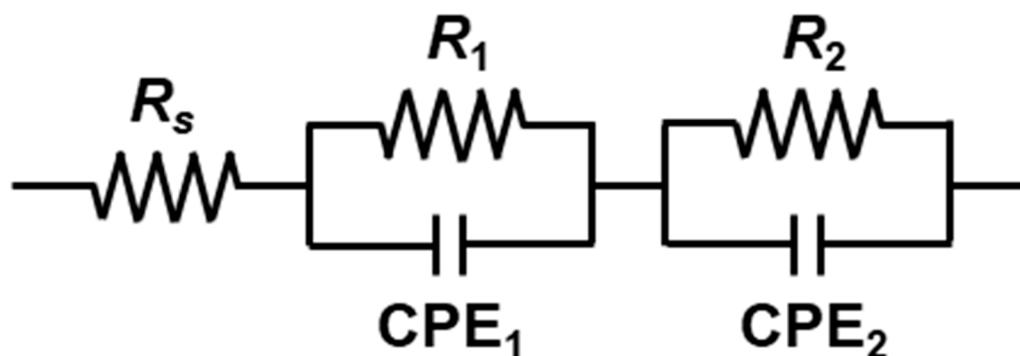


Figure S4. The equivalent circuit for EIS analysis.

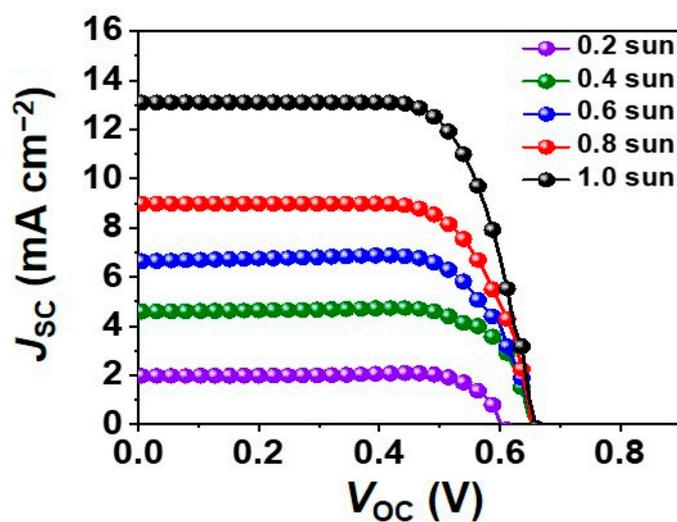


Figure S5. The $J-V$ curves of the OX enhanced SS-FDSSC under various illuminations of 0.2 to 1.0 sun.



Figure S6. Photographs showing bending test for the OX-enhanced SS-FDSSC.

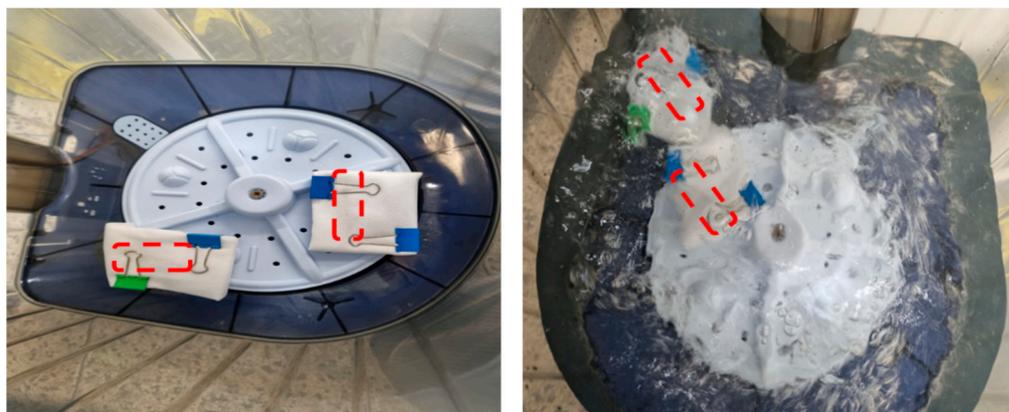


Figure S7. Photographs showing washing test for the OX-enhanced SS-FDSSC.

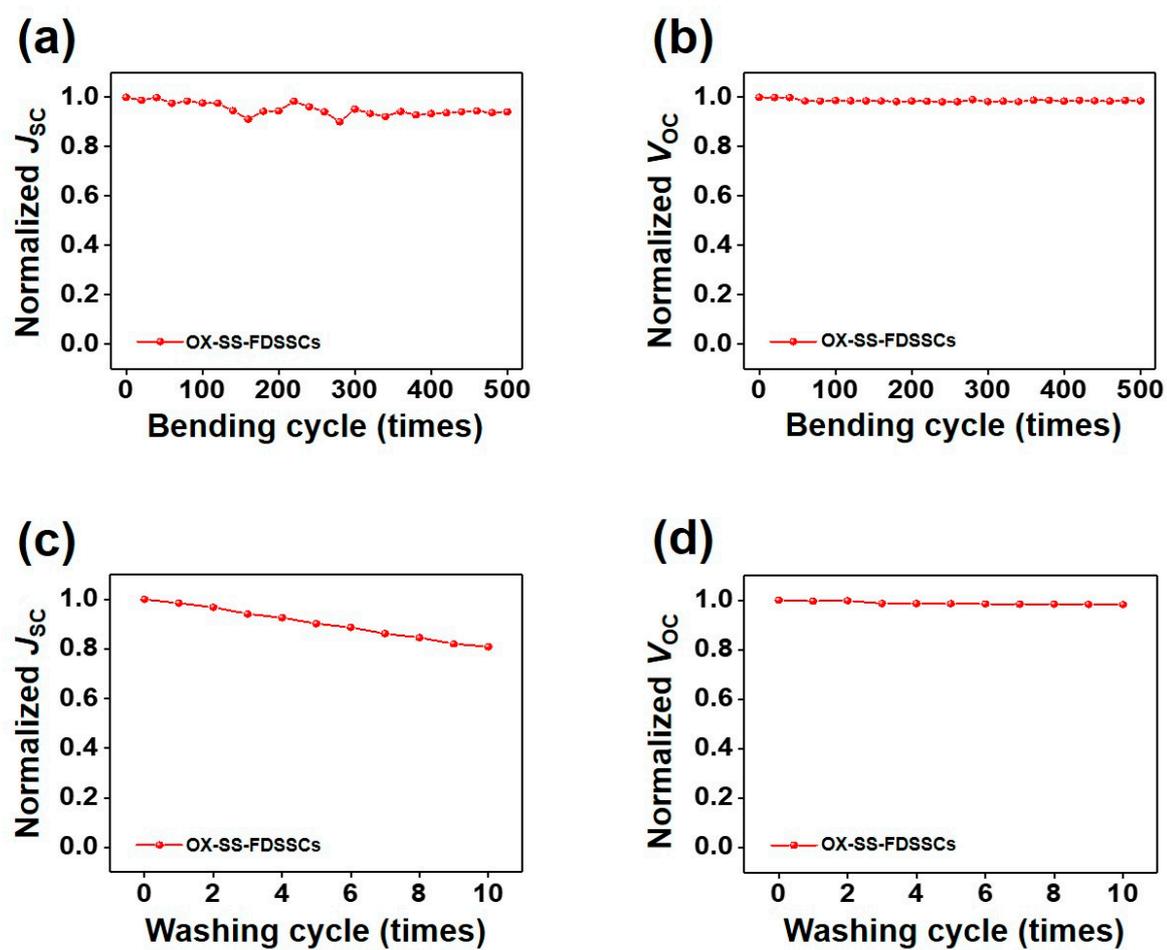


Figure S8. Normalized J_{sc} and V_{oc} of OX-enhanced SS-FDSSC as a function of (a) and (b) bending cycle, (c) and (d) washing cycle, respectively.

Table S1. EIS parameters of the SS-FDSSCs with TEMPO derivatives.

Device	R_s (Ω)	R_1 (Ω)	CPE ₁ (F)	R_2 (Ω)	CPE ₂ (F)
Pristine	25.0	41.5	3.36×10^{-6}	116	1.13×10^{-3}
OX	15.9	41.9	2.57×10^{-6}	104	1.38×10^{-3}
OAC	17.2	48.1	2.80×10^{-6}	144	9.44×10^{-4}
OBZ	19.9	39.3	2.87×10^{-6}	107	1.44×10^{-3}